

# Views on the 3D race-track memory



**Staffa Island, Scotland**

# Magnetic domain walls in cylindrical nanowires – Fundamental challenges for a 3D storage media

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[www.spintec.fr](http://www.spintec.fr)

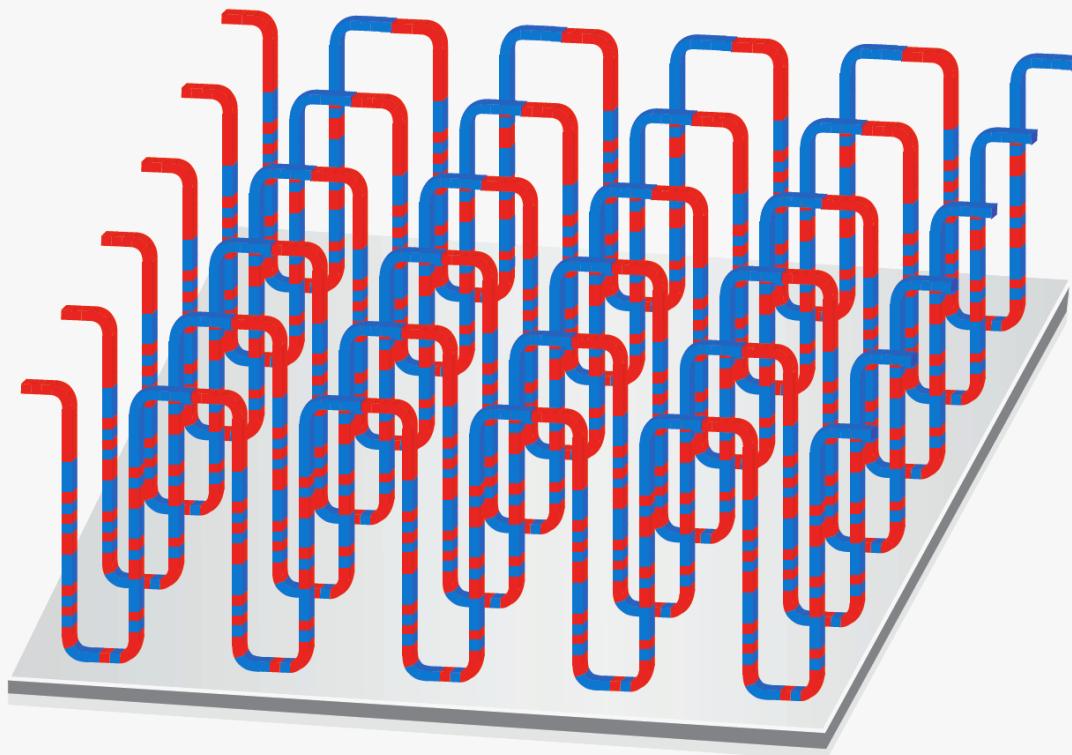


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*Slides:* <http://fruchart.eu/slides>



## Proposal for a 3D race-track memory



S. S. P. Parkin, Science 320, 190 (2008)  
Scientific American, June, 76 (2009)  
+ patents (IBM)

- What has been done?
- Dreams? Challenges?

Steady progress of HDD, however:  
incremental, keeping the design

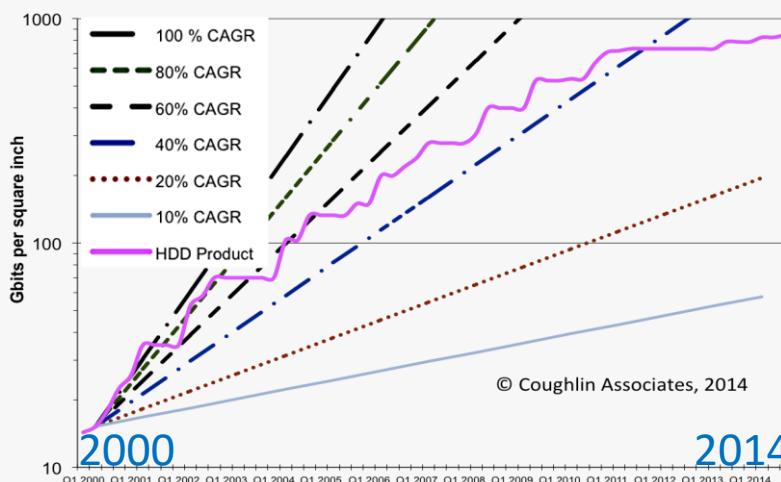


1956



Today

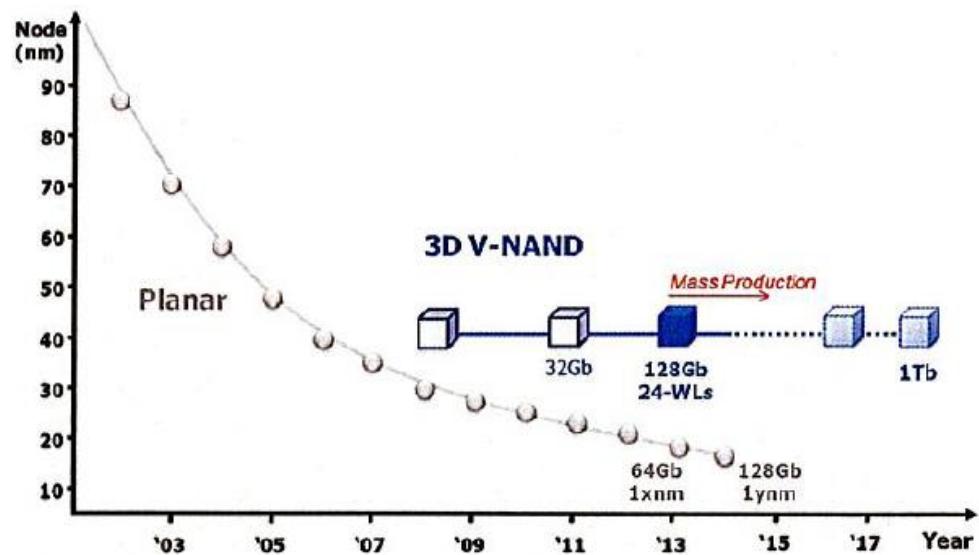
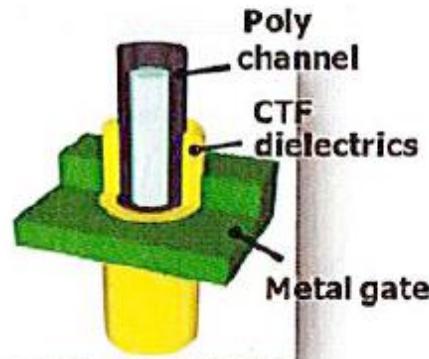
## Staggering areal density



- Increasing fundamental and technological bottlenecks
- Any 2D-based technology is bound to face an end

## Competing technologies go 3D

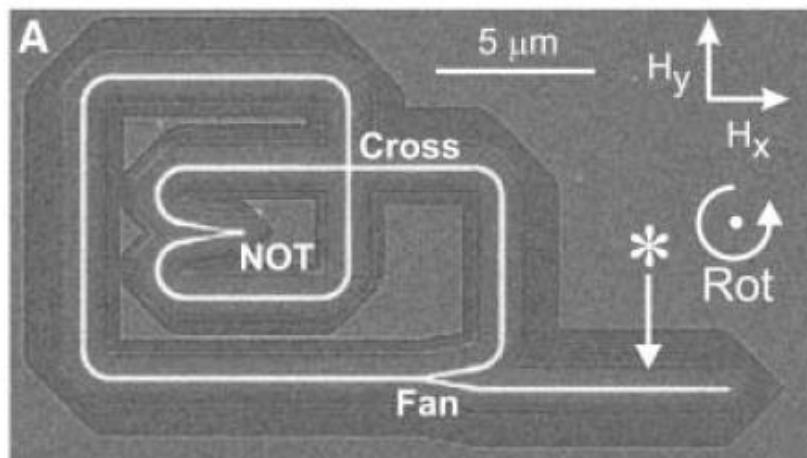
### 24-layer 3D NAND Flash



- $1\text{Gb}/\text{mm}^2 \rightarrow 600\text{Gb}/\text{in}^2\ldots$
- Magnetic mass storage may only remain for niche applications

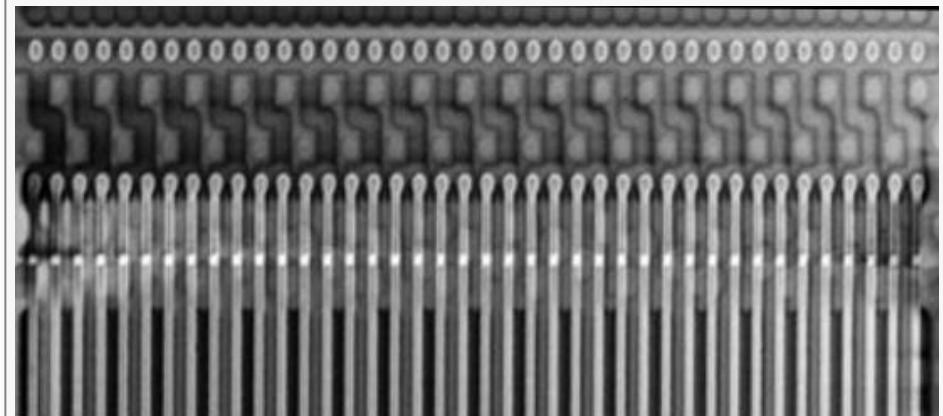
K. T. Park et al., IEEE J. Sol. State Circuits 50 (1), 204 (2015)

## Logic (field-driven)



D. A. Allwood et al., Science 309, 1688 (2005)

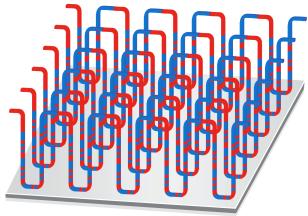
## Memory (current-driven)



L. Thomas et al., IEEE International Electron Devices meeting (2011)

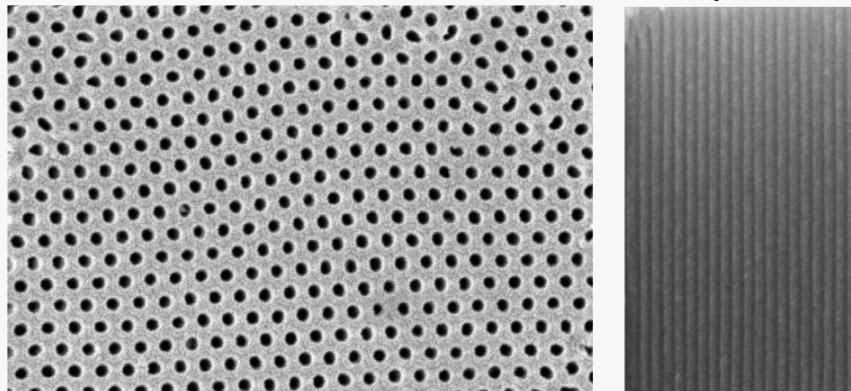
- 2D demonstrators. Competitive?
- 3D appealing. Probably a dream with very severe bottlenecks

## Motivation



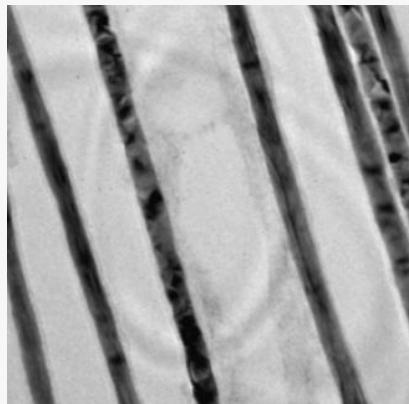
## Synthesis strategy

- Anodization of aluminum -> template



H. Masuda, Science 268, 1466-1468 (1995)

- Electroplating -> Magnetic wires



S. Da Col et al., APL 98, 112501 (2011)

Simple metals and alloys : Co, Ni,  $Fe_{20}Ni_{80}$ ,  $Co_{20}Ni_{80}$

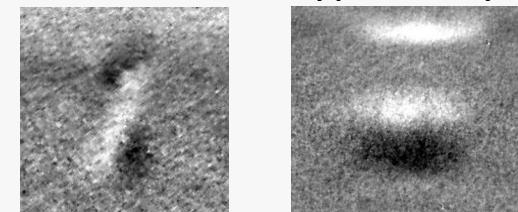
100nm

## Our focus: identify bottlenecks

- Synthesis: deep and structured pores

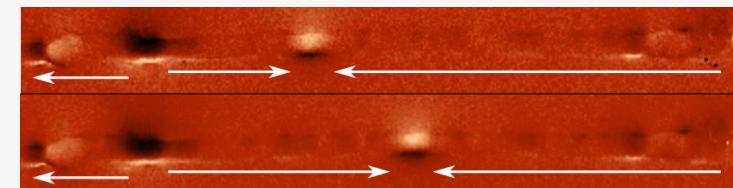


- Domain wall types in cylinders



S. Da-Col et al., PRB (R) 89, 180405, (2014)

- Move domain walls

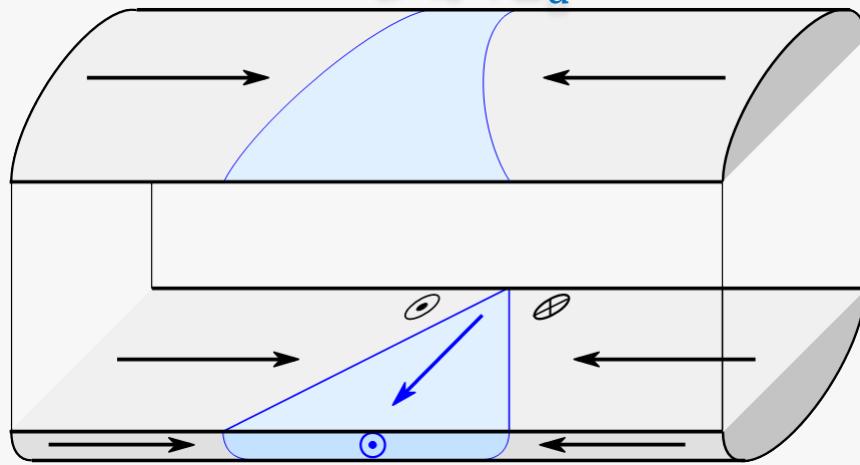


S. Da-Col et al., APL109, 062406 (2016)

- Tackle dipolar interactions



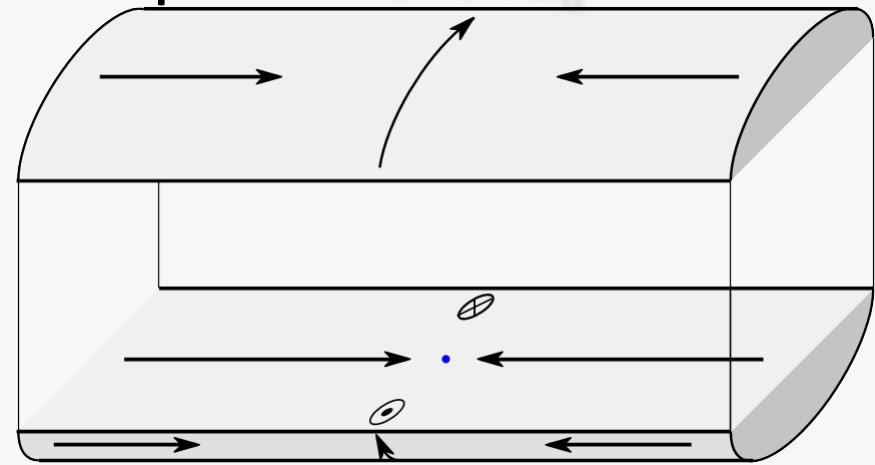
## Transverse wall $D \lesssim 7\Delta_d^2$



H. Forster et al., J. Appl. Phys. 91, 6914 (2002)

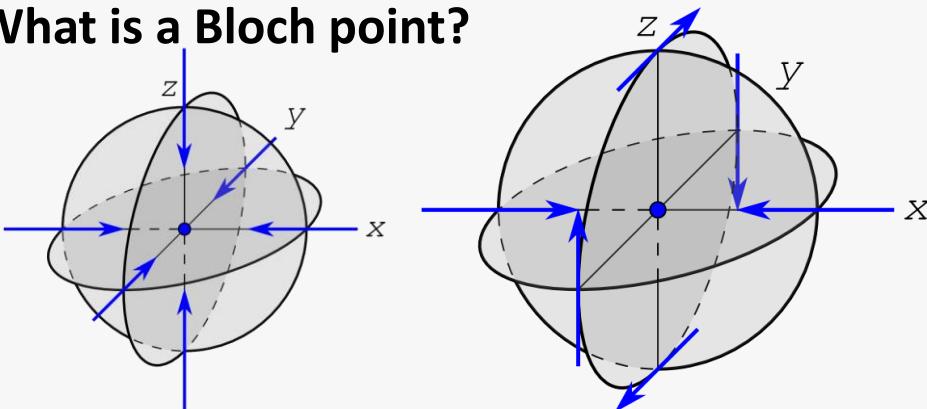
A. Thiaville, Y Nakatani / B. Hillebrands, A. Thiaville (ed.),  
Spin dynamics in confined magnetic structures III, 101, 161-206 (2006)

## Bloch-point wall $D \gtrsim 7\Delta_d^2$



Sometimes improperly called vortex wall

## What is a Bloch point?



A magnetization texture with local cancellation of the magnetization vector

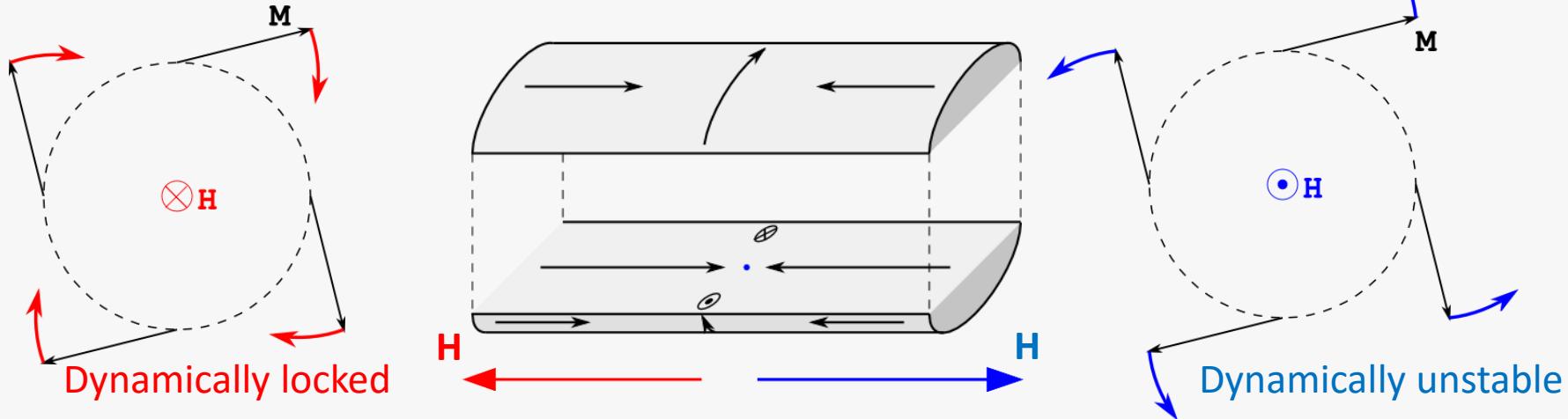
R. Feldkeller,  
Z. Angew. Physik 19, 530 (1965)

W. Döring,  
J. Appl. Phys. 39, 1006 (1968)

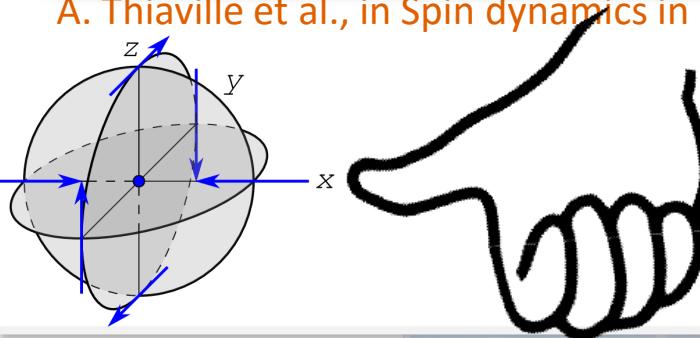
## LLG equation

$$\frac{d\mathbf{m}}{dt} = \gamma_0 \mathbf{m} \times \mathbf{H} + \alpha \mathbf{m} \times \frac{d\mathbf{m}}{dt} \quad \gamma_0 < 0$$

## 'Once-only' Walker event



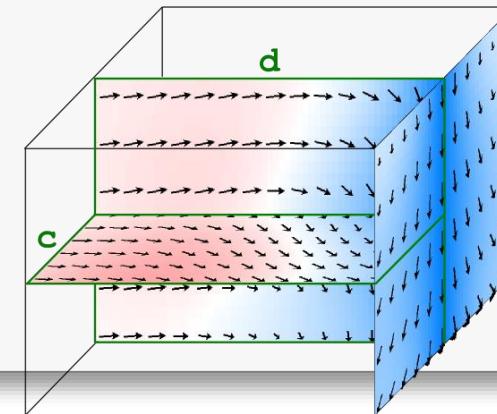
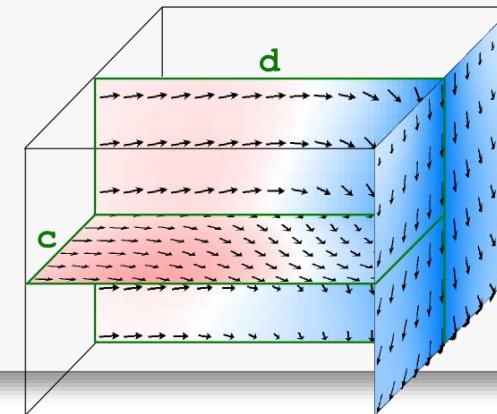
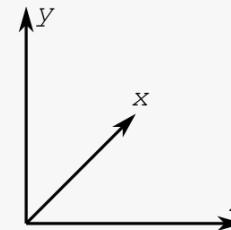
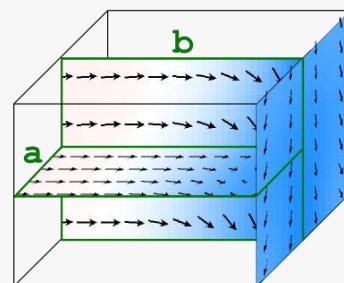
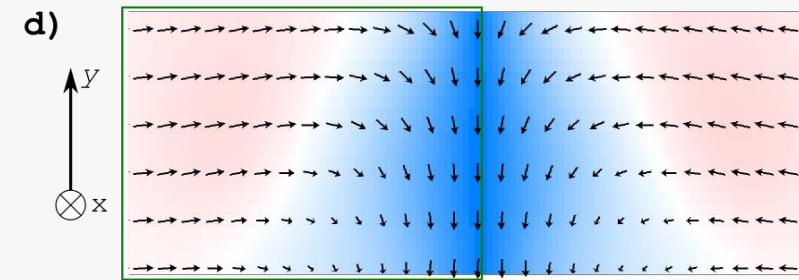
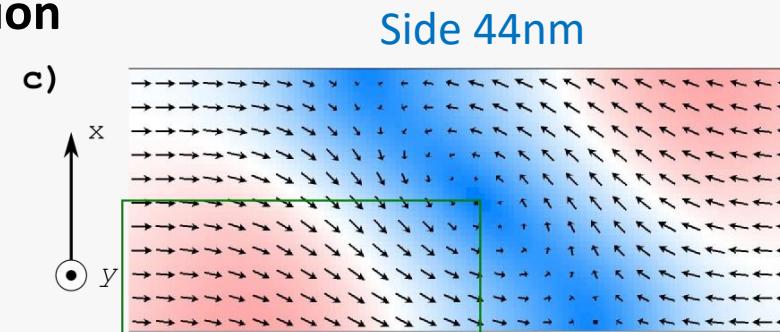
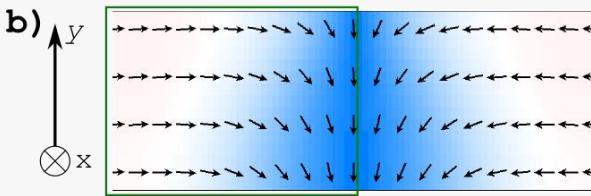
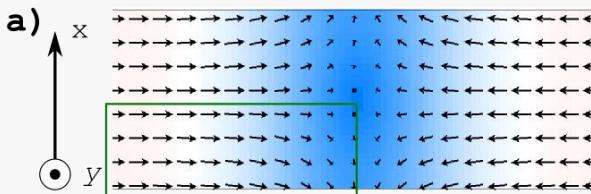
A. Thiaville et al., in Spin dynamics in confined magnetic structures III, p.161-206 (2006)



- 'Once-only' circulation Walker
- Right-hand rule vs direction of motion
- Same physics predicted (later) for tubes

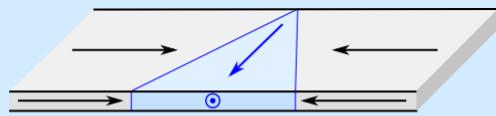
## Wires with square cross-section

Side 30nm

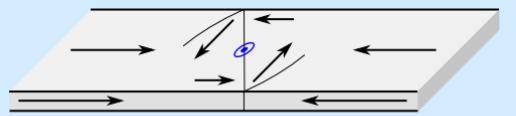


- Transverse walls have both transverse and vortex features

## Two topologies for domain walls



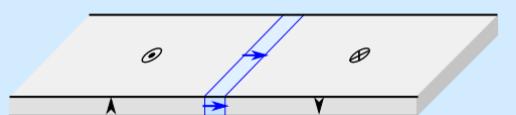
Transverse



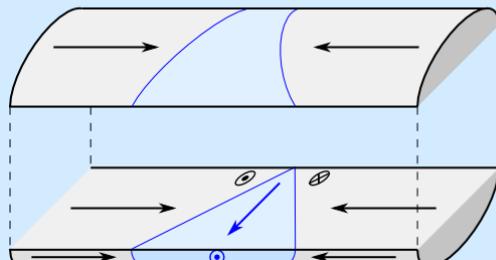
Vortex



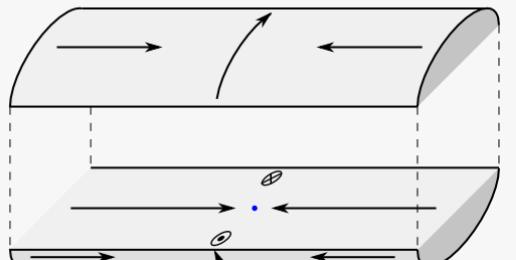
Bloch



Néel



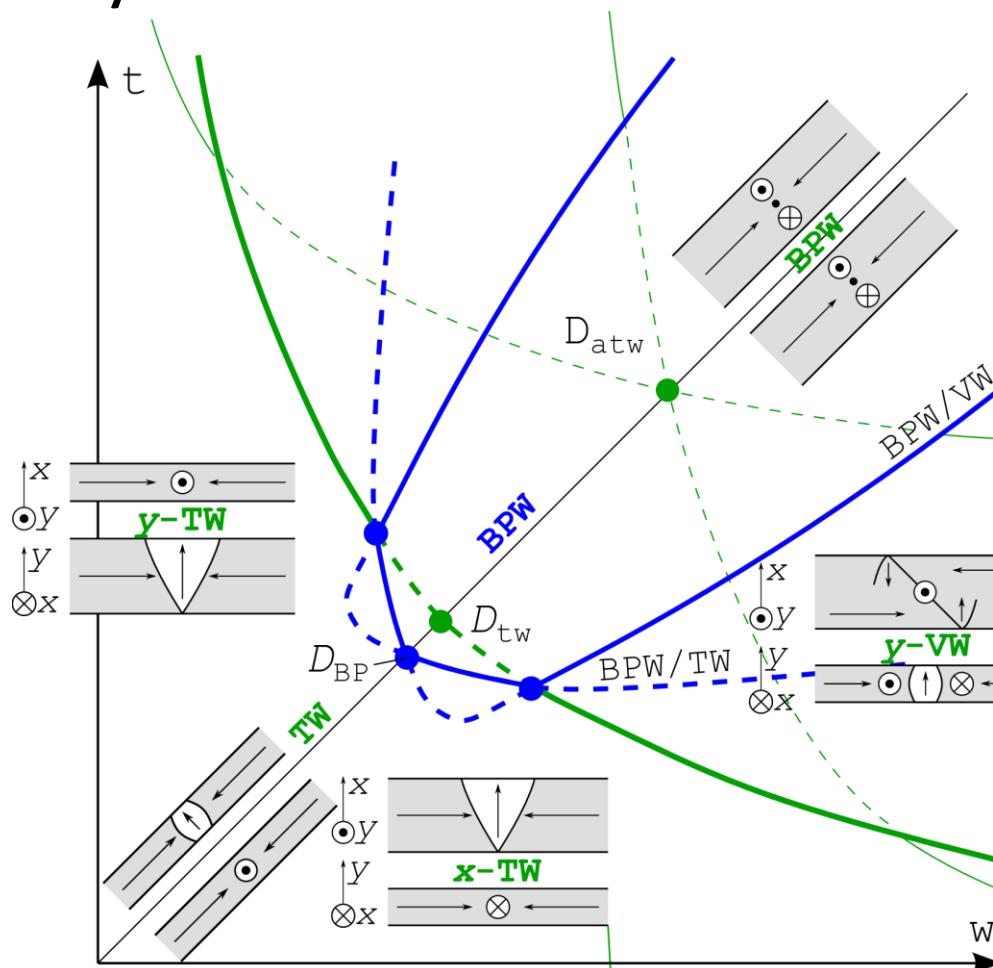
Transverse-Vortex (TVW)



Bloch-point (BPW)

- Transverse and vortex walls share the same topology
- Also identical to Bloch and Néel walls for perp magnetization
- Walker field = changes of texture within the same family
- Bloch-point walls have a different topology

## Analytics and simulation



Legend:

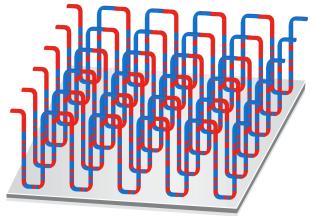
- Dashed blue line: 2nd order transitions
- Solid blue line: 1st order transitions
- Dashed green line: 2nd order transitions
- Solid green line: 1st order transitions

- Covers from flat strip to square/disk wires
- Bloch-point walls should exist for a wide range of non-circular wire

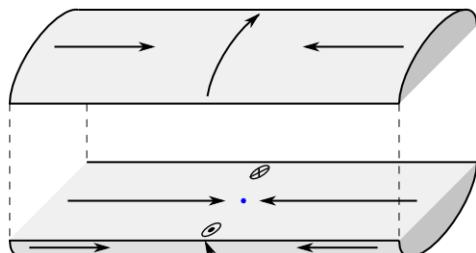


Review chapter : S. Jamet et al., in Magnetic Nano- and Microwires: Design, synthesis, properties and applications, M. Vázquez Ed., Woodhead (2015) (arXiv:1412.0679)

- Motivation

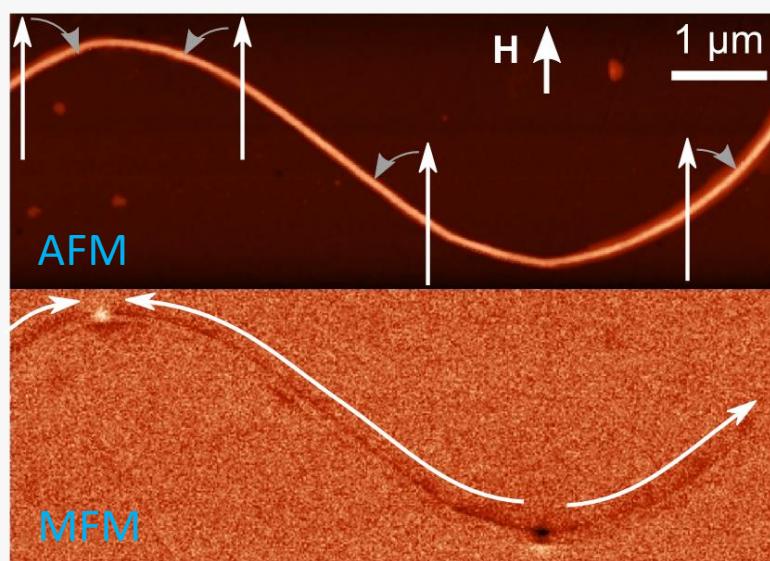


- Expectations for domain walls



## BOTTLENECK: how to nucleation domain walls in cylindrical wires?

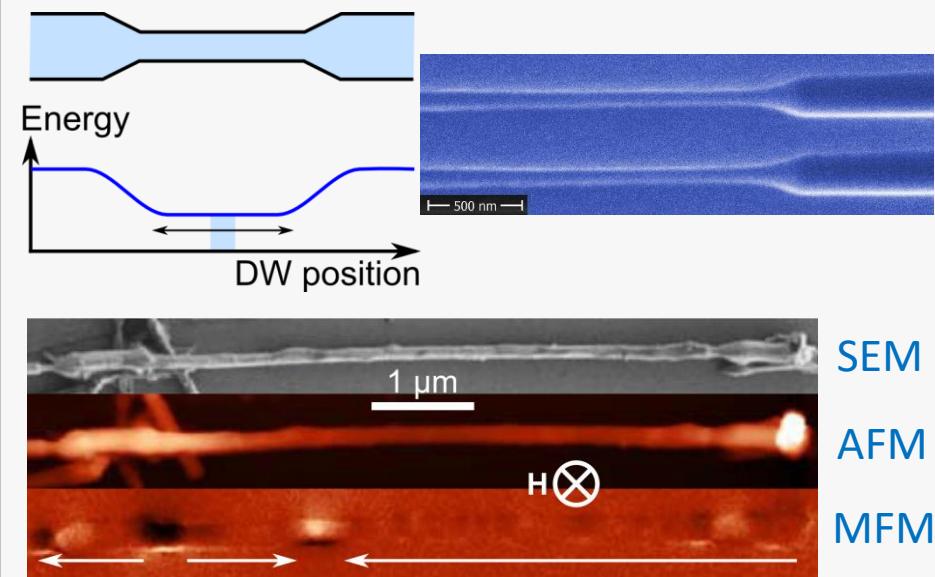
### Route 1: bends



NB: similar to procedure with strips

T. Taniyama, Phys. Rev. Lett. 82, 2780 (1999)

### Route 2: diameter modulations

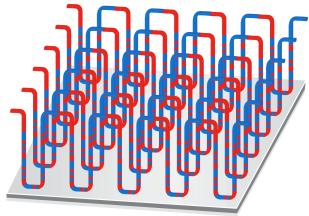


Increase of diameter induces an energy barrier for domain walls

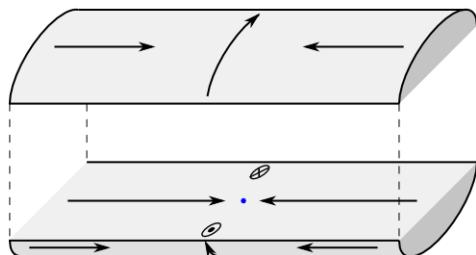


S. Da-Col et al., Appl. Phys. Lett. 109, 062406 (2016)

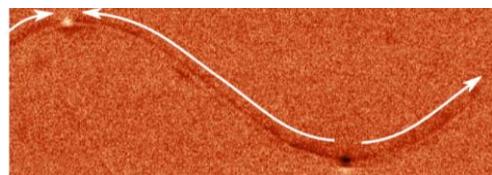
- Motivation



- Expectations for domain walls

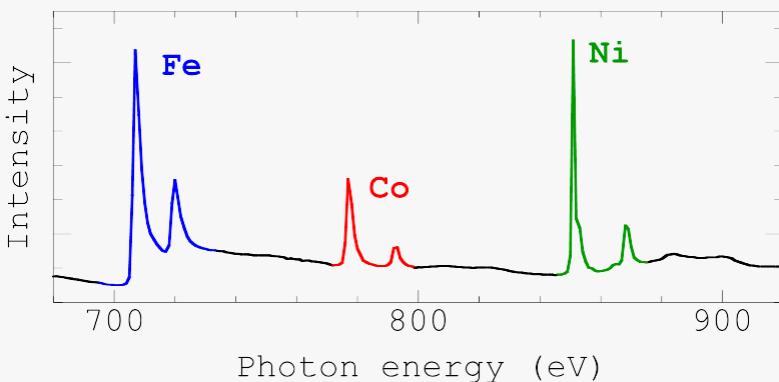


- Nucleate walls

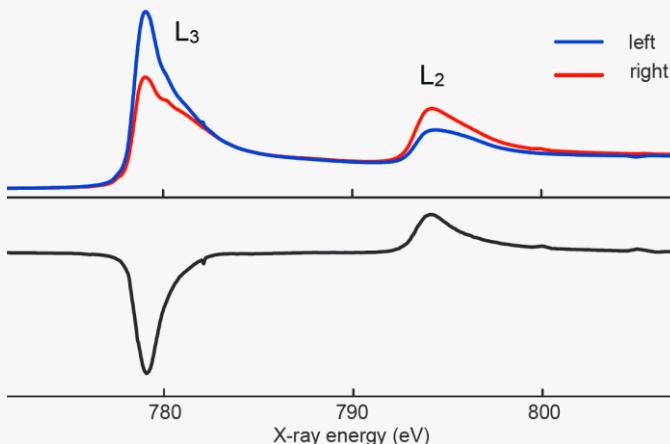


## X-Ray magnetic circular dichroism

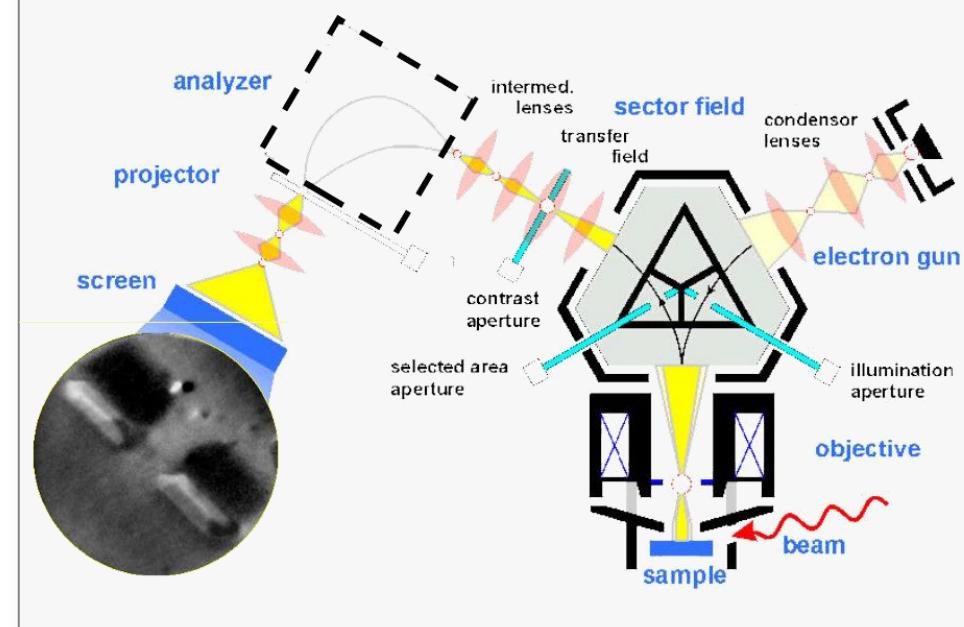
- Element selectivity



- Magnetic sensitivity



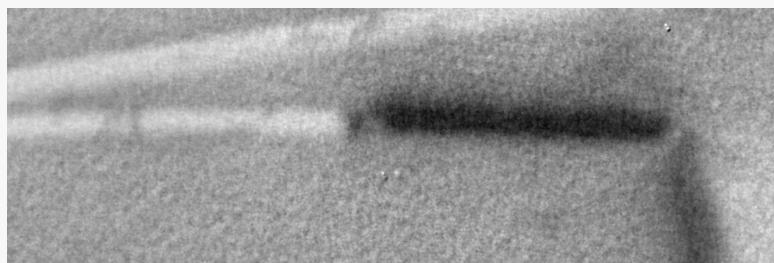
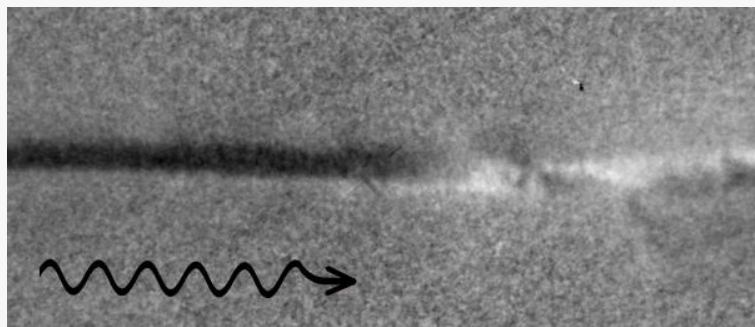
## Photo-Emission Electron Microscopy



- Synchrotron-based
- Secondary electrons -> surface sensitive
- 25nm resolution in best case

## Locate walls

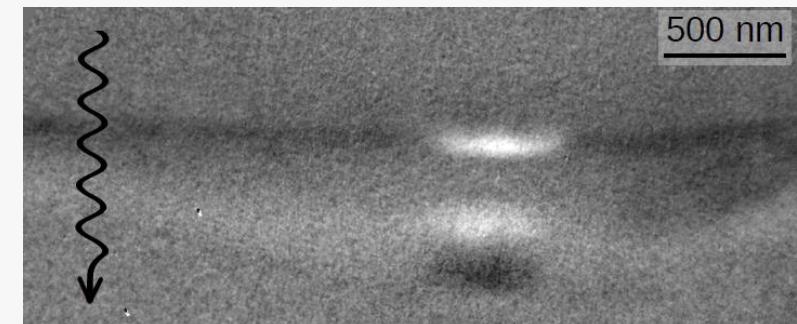
Beam along wire



FeNi

## Image domain walls

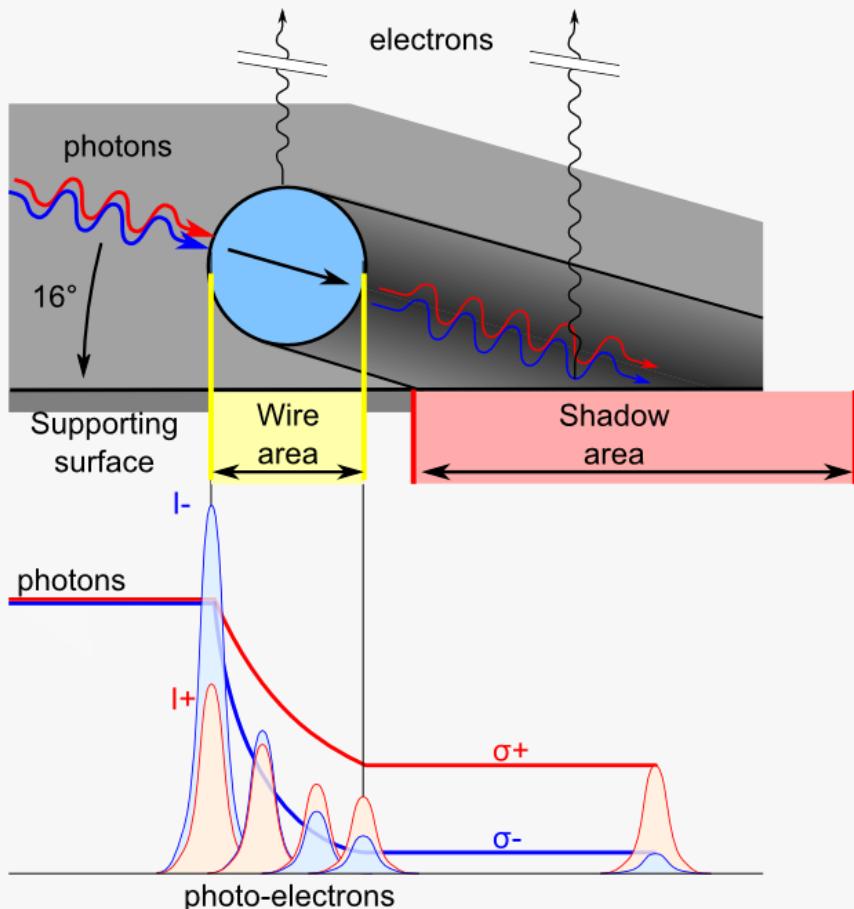
Beam across wire



FeNi

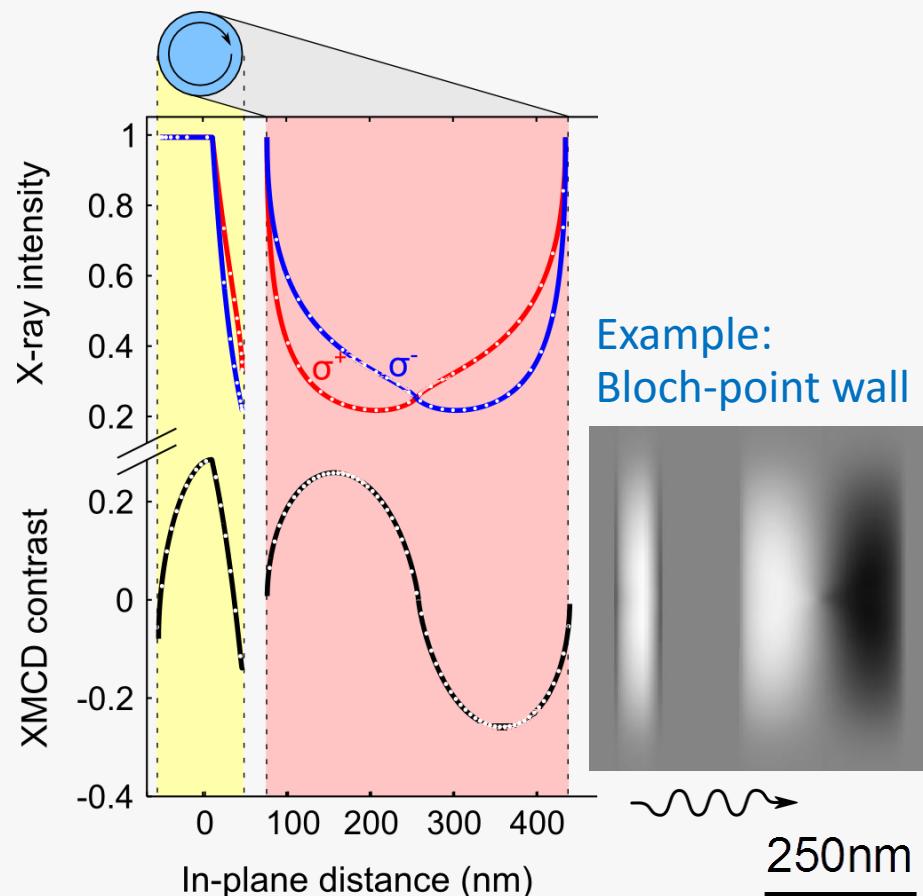
- Non-trivial patterns
- Need for modeling

## SHADOW XMCD-PEEM



S. Jamet et al., PRB92, 144428 (2015)

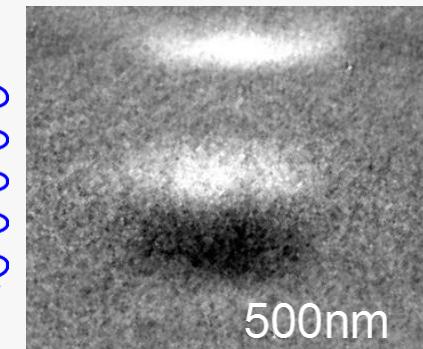
## SIMULATION OF CONTRAST



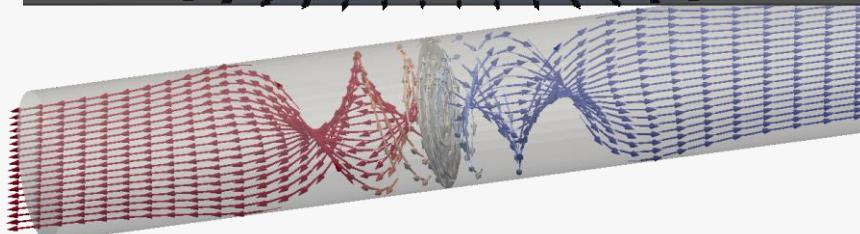
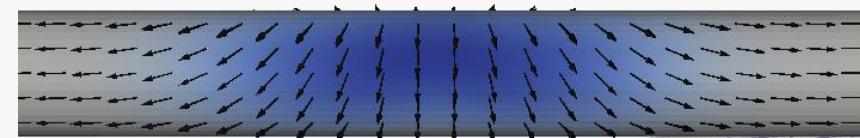
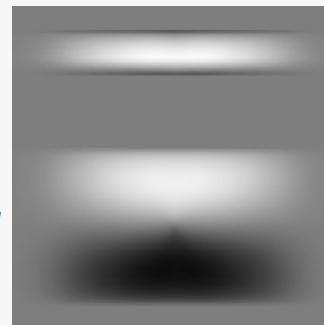
Example:  
Bloch-point wall

## Bloch-point walls

### Experiment



### Simulation



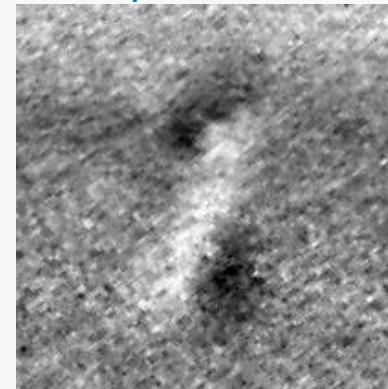
- ❑ Orthoradial curling
- ❑ Symmetry with respect to plane perpendicular to axis



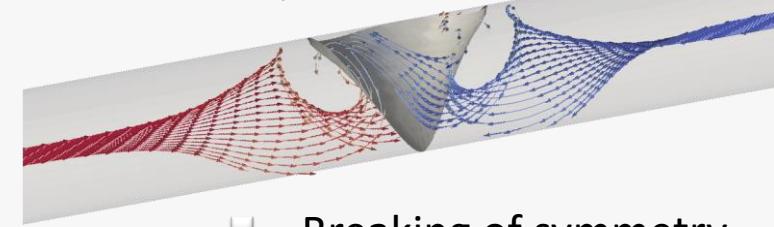
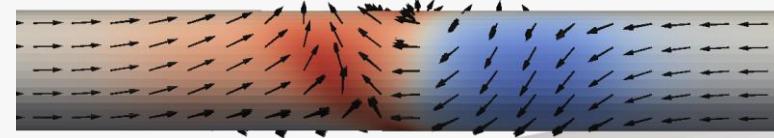
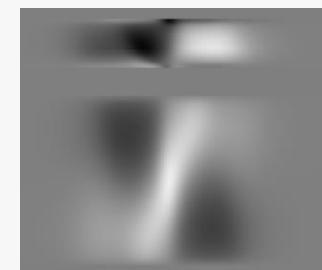
S. Da-Col et al., Phys. Rev. B (R) 89, 180405, (2014)

## Transverse walls

### Experiment



### Simulation

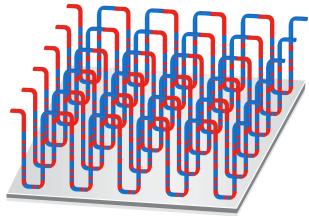


- ❑ Breaking of symmetry

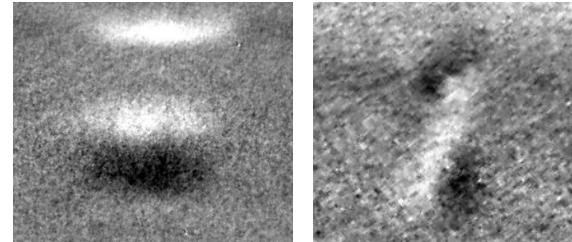
Also imaged with electron holography:

N. Bizières et al., Nanolett. 13, 2053 (2013)

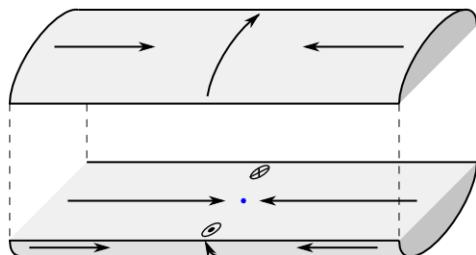
- Motivation



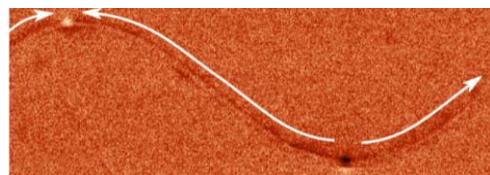
- Identify walls



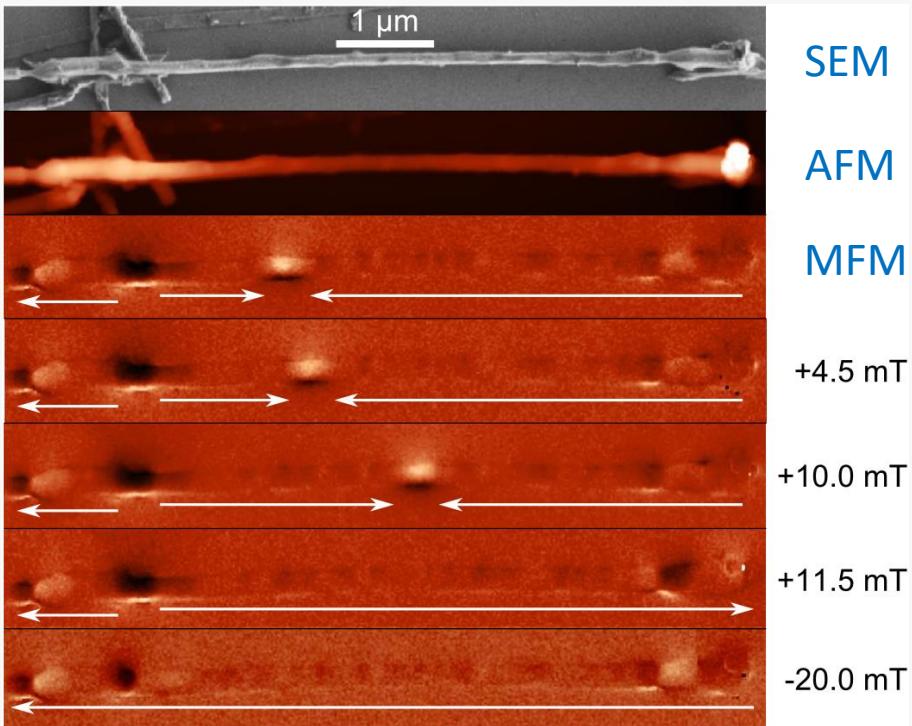
- Expectations for domain walls



- Nucleate walls



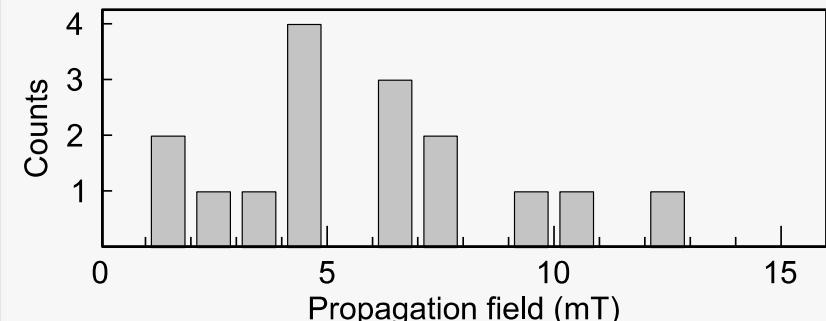
## Quasistatic motion



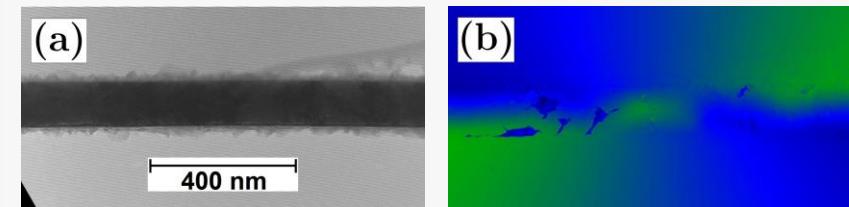
S. Da-Col et al.,  
Appl. Phys. Lett. 109, 062406 (2016)

## Pinning fields

### Measured distribution

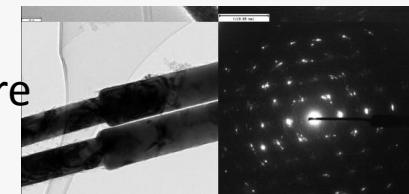


### Electron holography – No clear correlation with structure



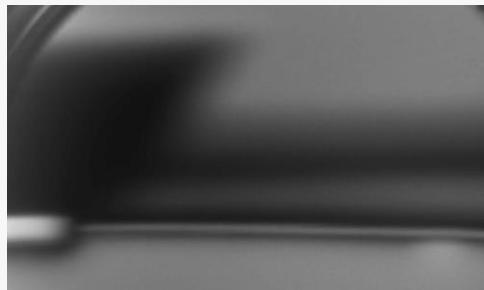
M. Staňo et al., JMMM, submitted

### Optimization of material / structure

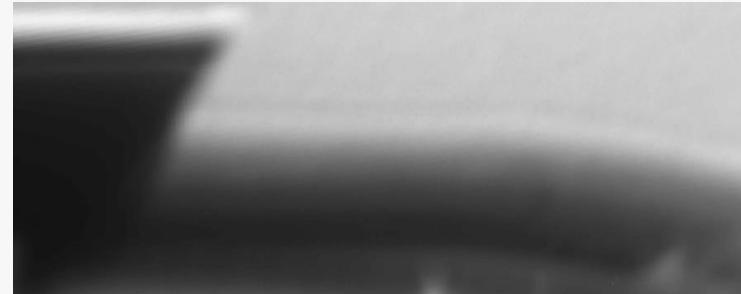


## Modulated diameter to keep domain walls in wire

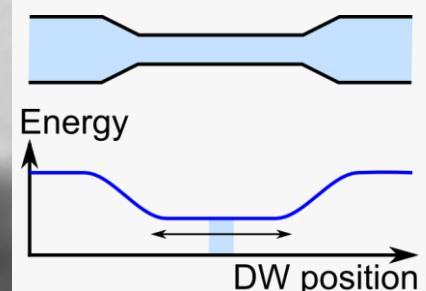
Focus on wire



Focus on shadow

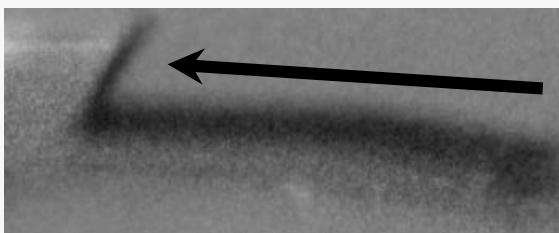


CoNi

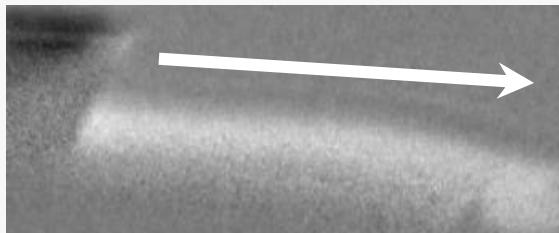


## Selection of circulation (to be confirmed)

Initial

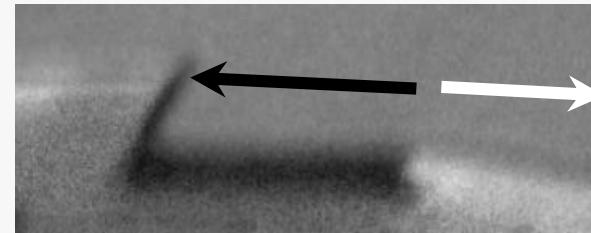
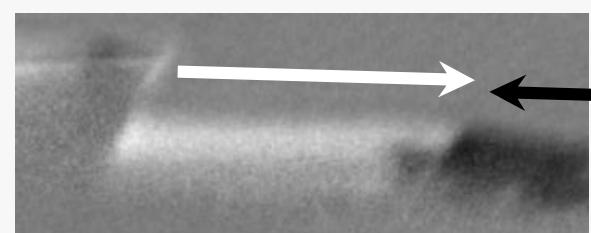


Field pulse  
→



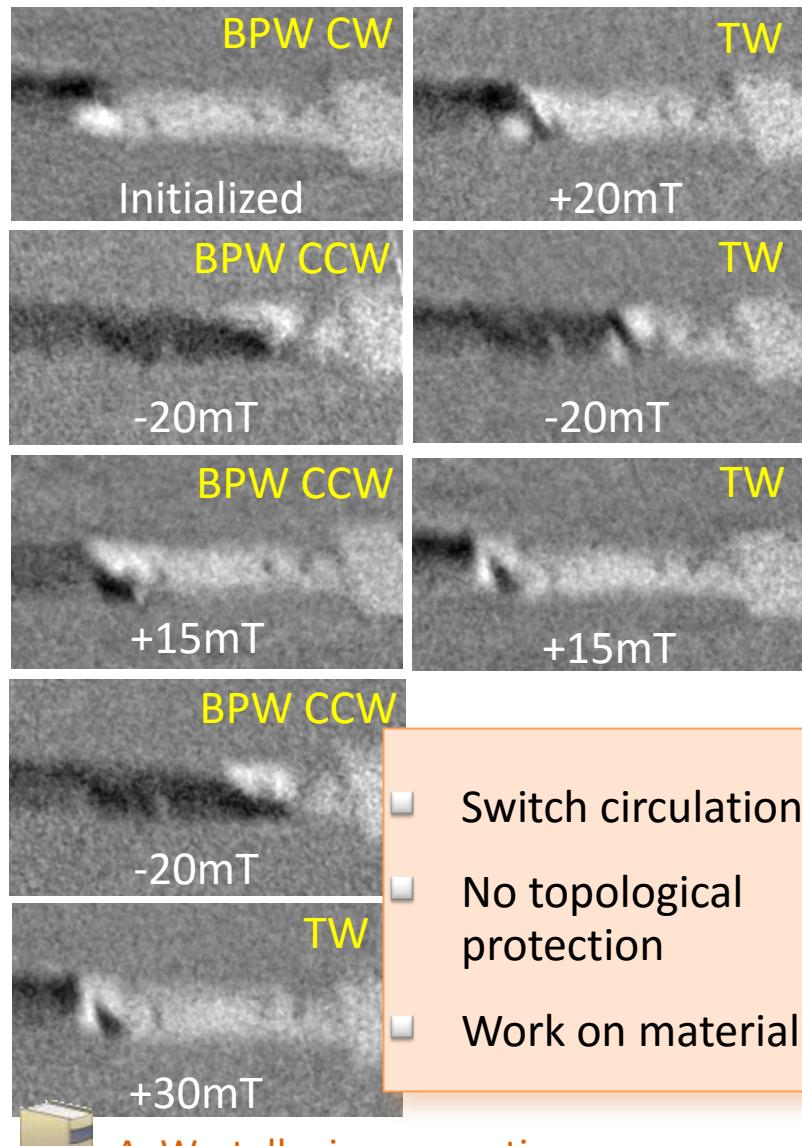
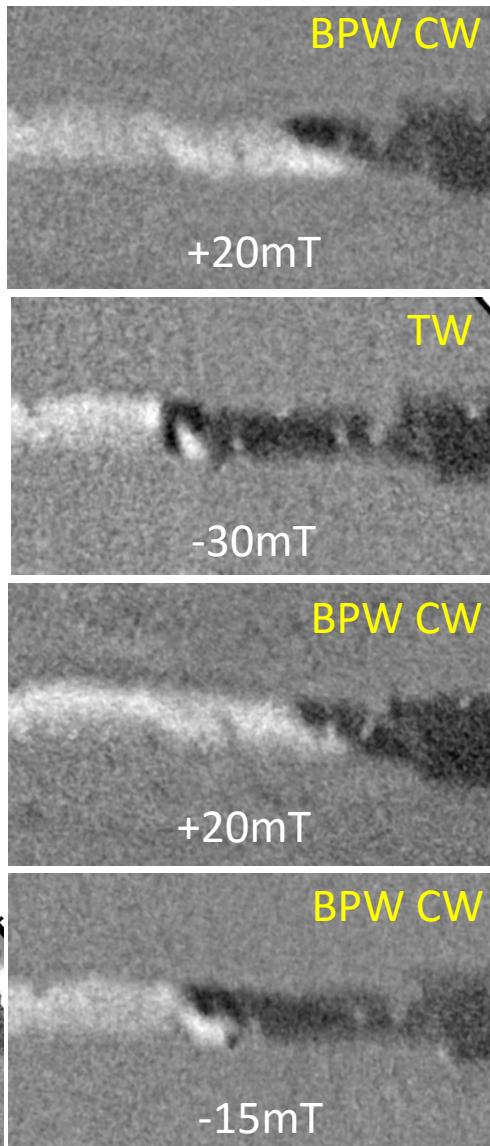
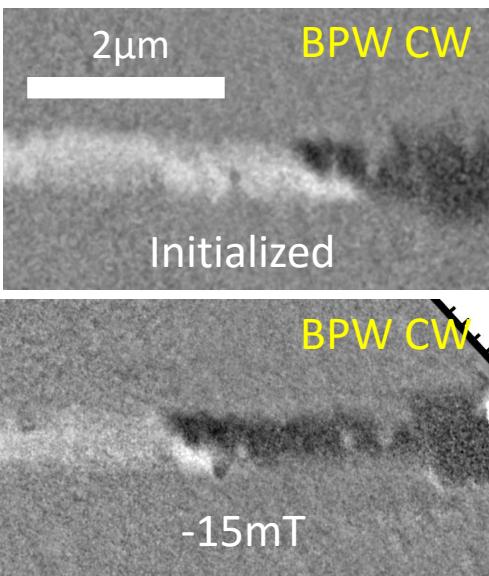
Field pulse  
←

Final





THE DARK SIDE



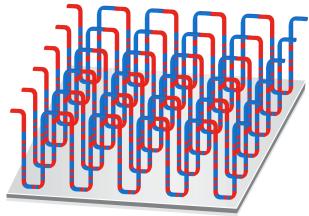
- Switch circulation
- No topological protection
- Work on material

A. Wartelle, in preparation

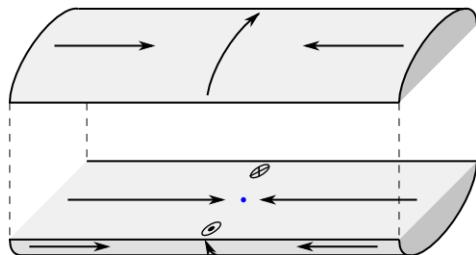


1<sup>st</sup> Sep. 2016  
SPIE 2016 Spintronics – San Diego

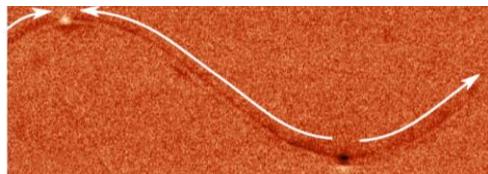
- Motivation



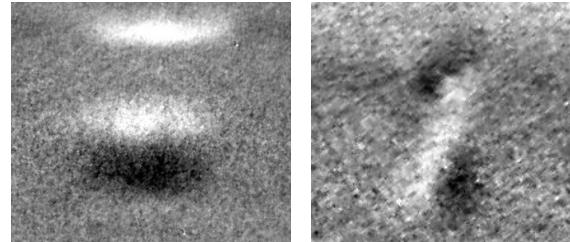
- Expectations for domain walls



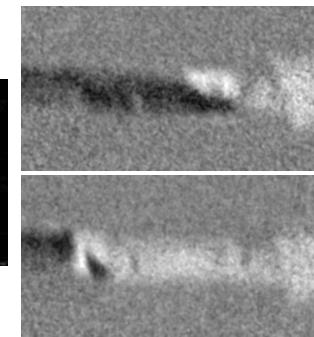
- Nucleate walls



- Identify walls

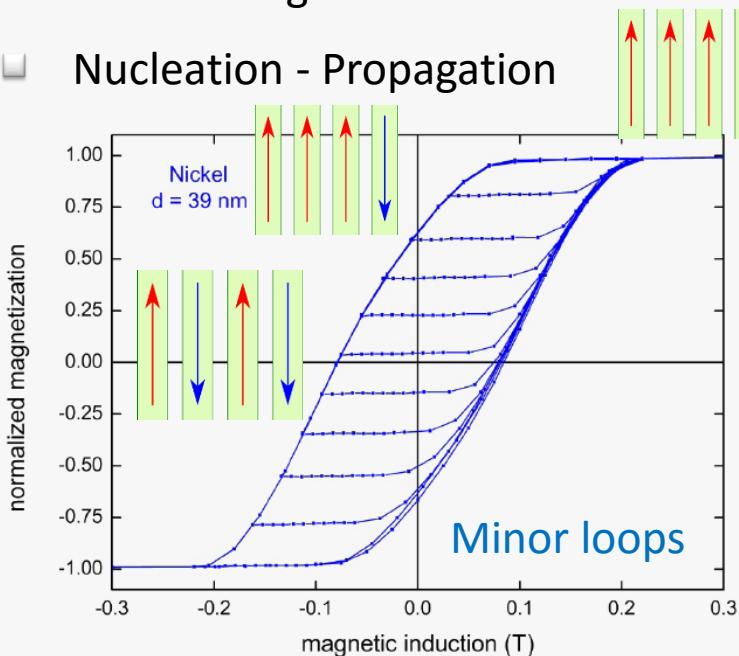


- Move walls

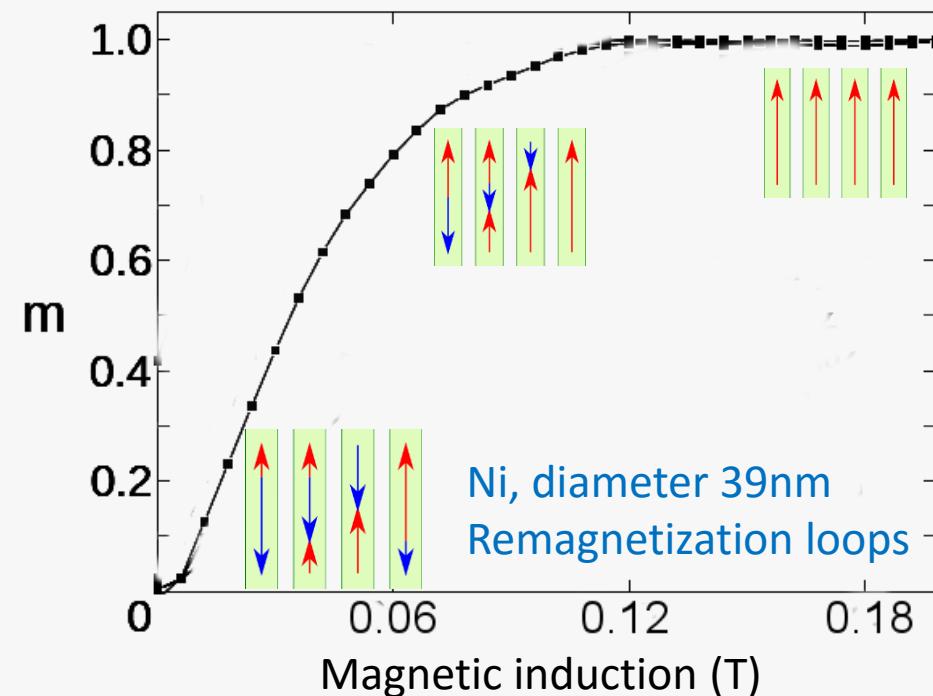


## Magnetization process

- Dominated by shape anisotropy for soft magnetic materials
- Nucleation - Propagation



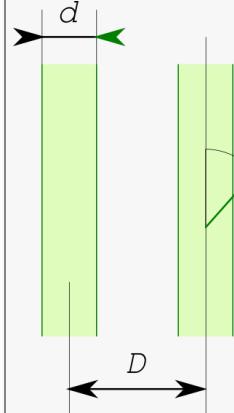
## Applies to remagnetization with wall motion



- Shear largely dominated by inter-wire dipolar interactions  
-> Cross-talk

- Solutions are needed to avoid cross-talk

## Shear related to demagnetization factor



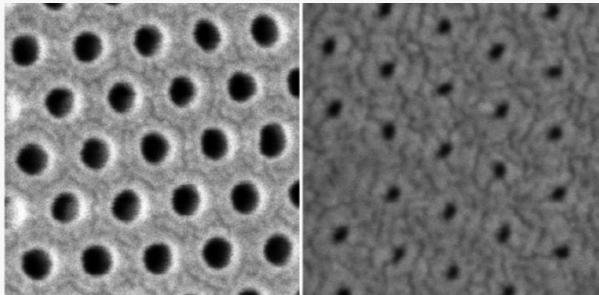
$$E_d = \frac{1}{2} \mu_0 M_s^2 \left( \frac{3p - 1}{2} \right) \cos^2 \theta$$

$$\text{Matrix porosity: } p = \frac{\pi}{2\sqrt{3}} \left( \frac{d}{D} \right)^2$$

A. Encinas-Oropesa et al., PRB 63, 104415 (2001)

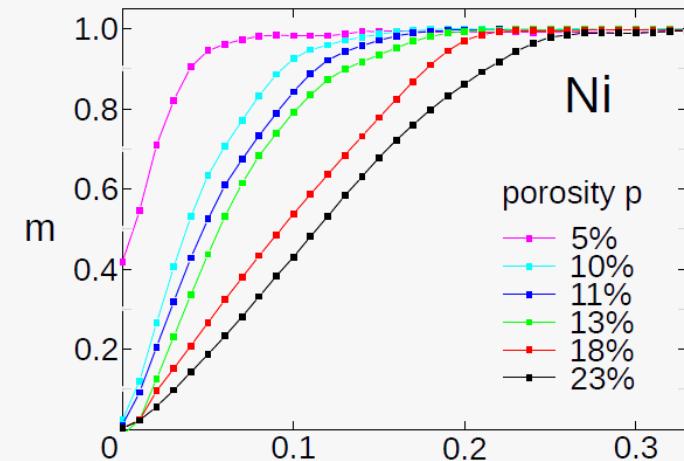
## Reduce porosity

- Apply atomic layer deposition to reduce inner diameter at constant pitch

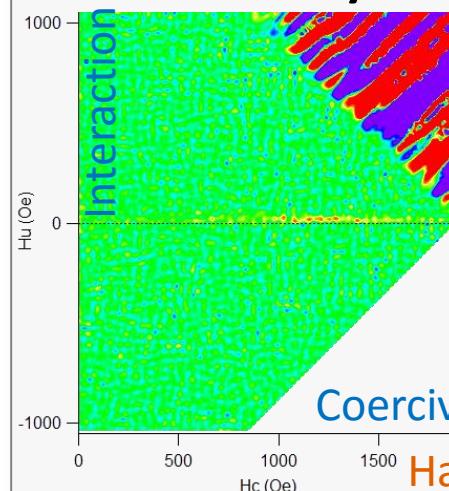


S. Da Col et al., APL 98, 112501 (2011)

## Application to domain walls



## Scalable to very low porosity



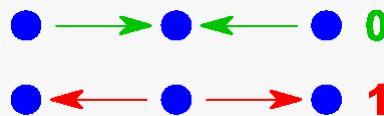
$$p = 0.3\%$$

FORC  
measurements

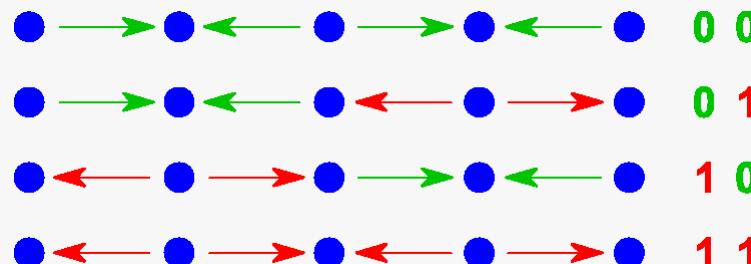
Coll. Univ.  
Hamburg & Erlangen

## 3D matrix needs to be globally with zero moment to avoid long-range cross-talks

- Basic building block with zero moment



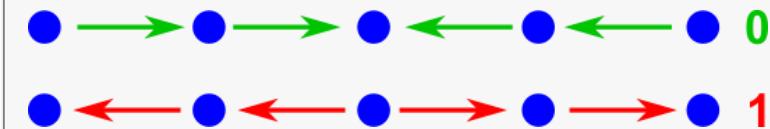
- Here: one bit per two physical sites
- Example, two bits:



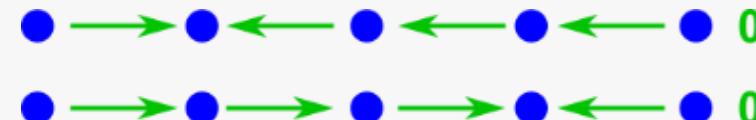
$4 = 2^2$  states

 4 sites per two bits

## Can be extended to fault-tolerant coding



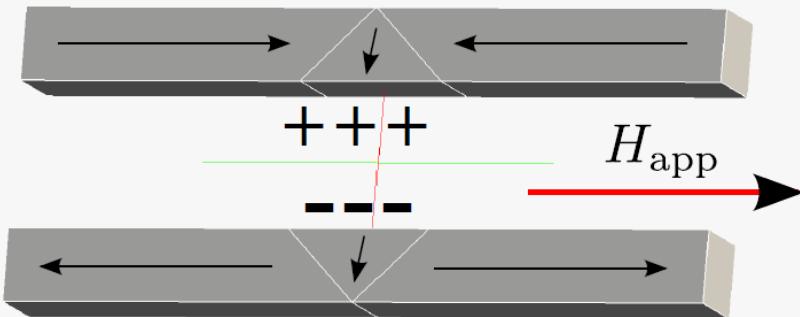
- The transition and its polarity are not lost if a DW is not shifted, or shifter twice



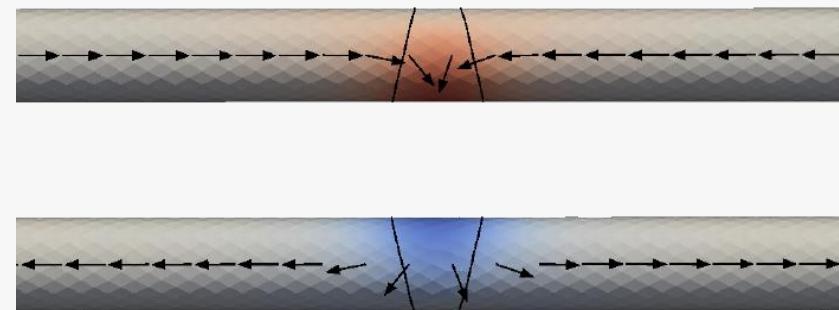
- Hardware solution not necessary for global interaction. But...

Intra-wire and inter-wire interactions remain between neighboring domain walls

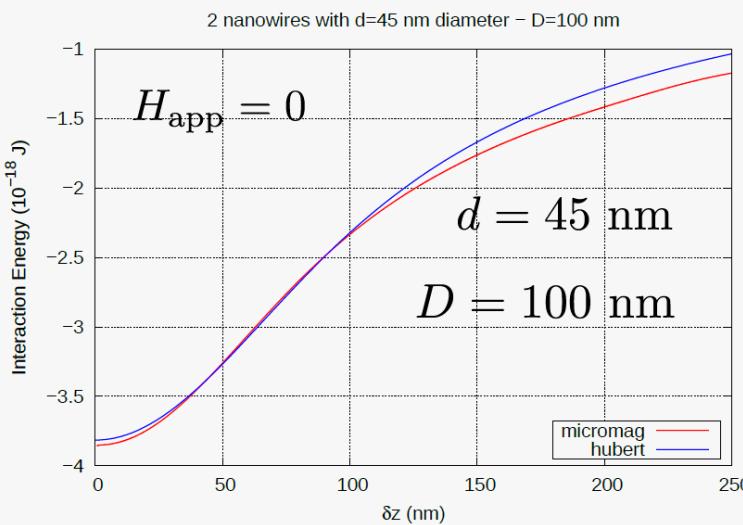
## Analytical modeling



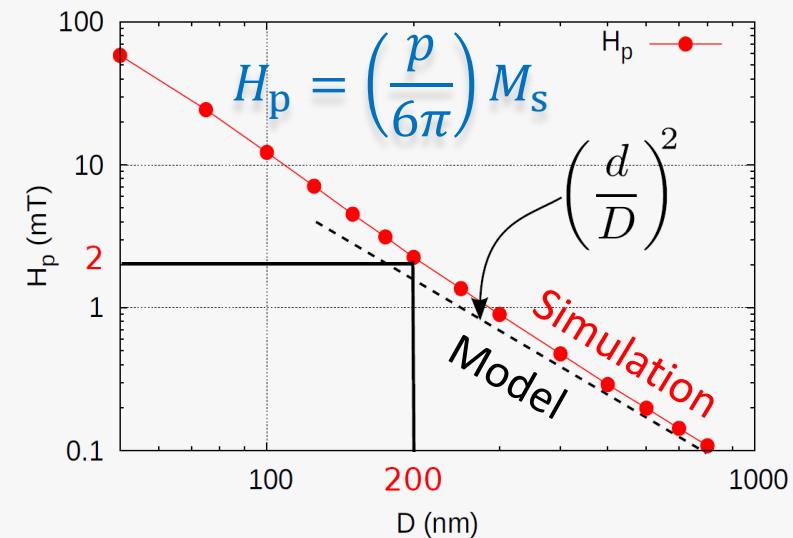
## Micromagnetic simulations



## Interaction energy



## Scaling law for interaction field



## Simple discussion based on inter-wire interaction

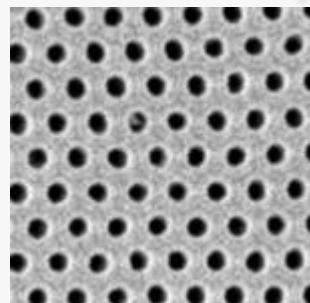
- One neighbor:

$$H_d = \left( \frac{p}{6\pi} \right) M_s$$

$$p = \frac{\pi}{2\sqrt{3}} \left( \frac{d}{D} \right)^2$$

- Six neighbors:

$$H_d = \left( \frac{p}{\pi} \right) M_d$$



## Longer range: each bit seen as a quadrupole

- Field due to dipole:  $H_\mu \approx \frac{1}{4\pi R^3} \frac{\pi d^2}{4} \lambda M_s$

$$H_Q \approx \frac{3}{16} \frac{d^2 \lambda^2}{R^4} M_s$$

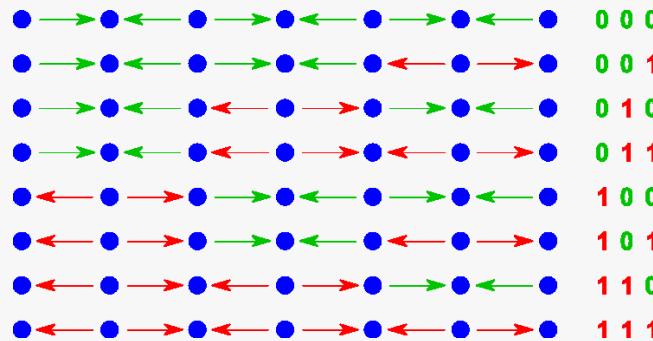
- Field due to quadrupole:
- Upper bound for integrated quadrupoles:  $H_d \approx 3\pi p M_s$

- Still, hardware reduction of porosity is important

## Underway

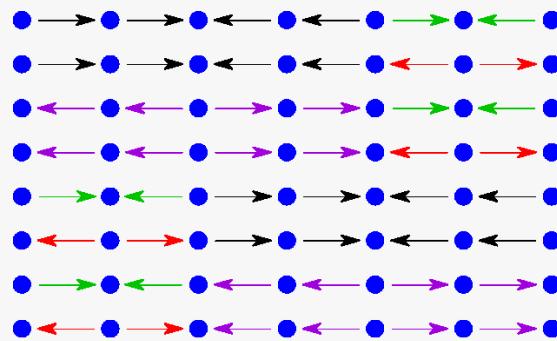
- Counting all possible states
- Provide exact number for interaction field
- Highlight distribution tails and rare configurations

## Example of zero-moment states not covered



$8 = 2^3$  states

6 sites per three bits



Extra 8 states per 6 sites

- 6 sites per 4 bits
- 1.5 sites per bit



O. Fruchart,  
in preparation

## Generalization

Number of bits per site for  $\ell$  sites

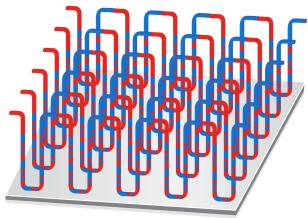
$$n_{\text{bps}} = \frac{\ln(N_{\text{states}})}{\ell \ln 2}$$

- May increase quadrupolar cross-talk
- Makes the counting algorithm important

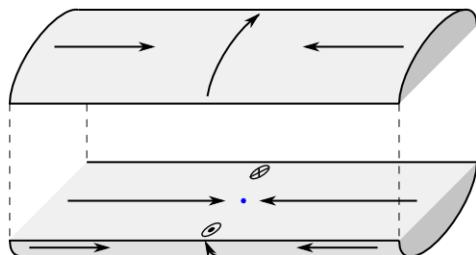


# DISCUSSED TODAY

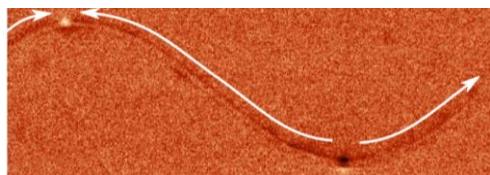
## ■ Motivation



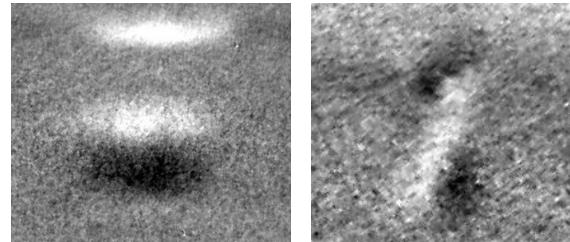
## ■ Expectations for domain walls



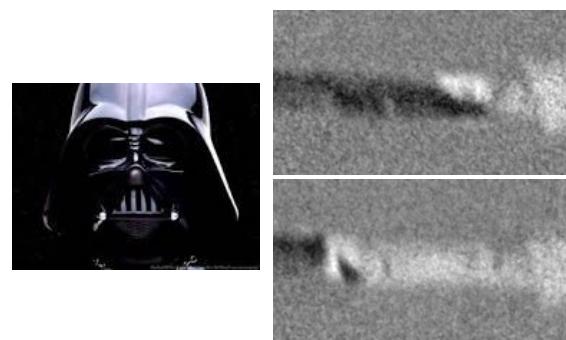
## ■ Nucleate walls



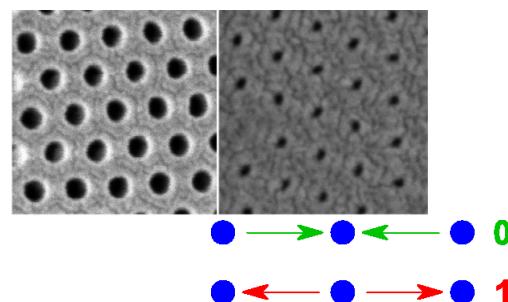
## ■ Identify walls



## ■ Move walls

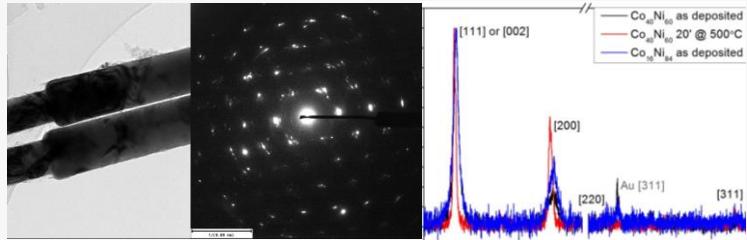


## ■ Reduce interactions



## Physics of wall motion

- Material science – Reduce defects

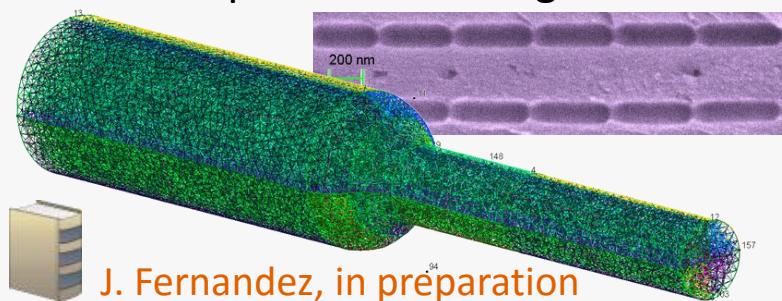


- Determine wall mobility



## Walls in segments

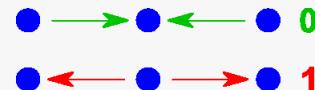
- Develop robust clocking schemes



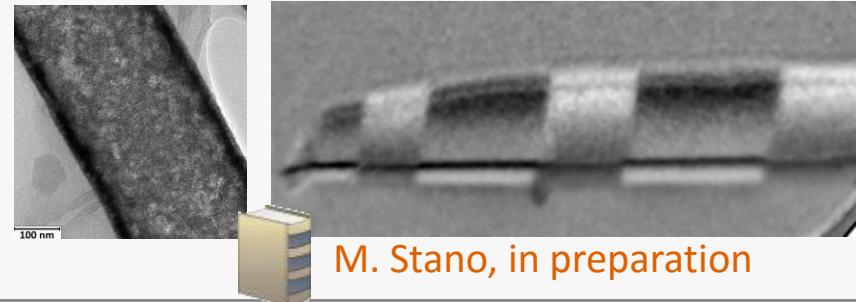
J. Fernandez, in preparation

## Reduce interaction

- Determine best algorithm

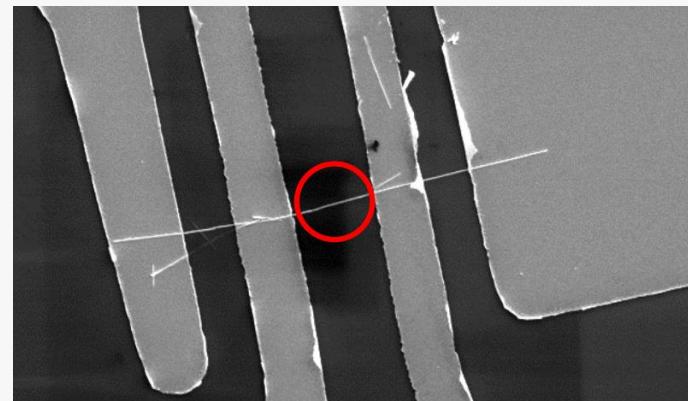


- New routes – Flux-closure nanotubes



M. Stano, in preparation

## Move towards spintronics



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# Thank you for your attention !

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